

T835H, T850H

High temperature 8 A Snubberless™ Triacs

Features

- Medium current Triac
- 150 °C max. T_j turn-off commutation
- Low thermal resistance with clip bonding
- Very high 3 quadrant commutation capability
- Packages are RoHS (2002/95/EC) compliant
- UL certified (ref. file E81734)

Applications

Especially designed to operate in high power density or universal motor applications such as vacuum cleaner and washing machine drum motor, these 8 A Triacs provide a very high switching capability up to junction temperatures of 150 °C.

The heatsink can be reduced, compared to traditional Triac, according to the high performance at given junction temperatures.

Description

Available in through-hole or surface mount packages, the T835H and T850H Triacs series are suitable for general purpose mains power ac switching.

By using an internal ceramic pad, the T8xxH-6I provides voltage insulation (rated at 2500 V rms).

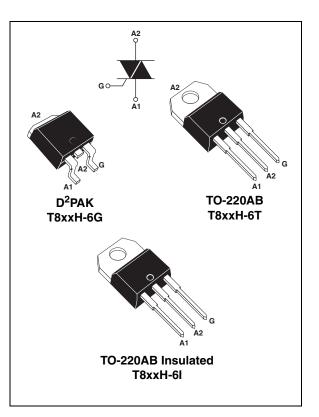


Table 1	۱.	Device	summary
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Symbol	Value	Unit
I _{T(RMS)}	8	А
V _{DRM} /V _{RRM}	600	V
I _{GT}	35 or 50	mA

TM: Snubberless is a trademark of STMicroelectronics

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1 Characteristics

Symbol	Parame	Parameter				
	On state rms surrent (full sine ways)	D ² PAK, TO-220AB		_c = 136 °C 8		
IT(RMS)	On-state rms current (full sine wave)	TO-220AB Ins	T _c = 123 °C	0	A	
1	Non repetitive surge peak on-state		t = 20 ms	80	А	
ITSM	current (full cycle, T _j initial = 25 °C)	F = 60 Hz	t = 16.7 ms	84	A	
l ² t	I ² t Value for fusing	t _p = 10 ms		42	A ² s	
dl/dt	Critical rate of rise of on-state current I_{G} = 2 x $I_{GT}, t_{r} \leq 100 \text{ ns}$	F = 120 Hz	T _j = 150 °C	50	A/µs	
V _{DSM} /V _{RSM}	Non repetitive surge peak off-state voltage	t _p = 10 ms	T _j = 25 °C	V _{DRM} /V _{RRM} + 100	V	
I _{GM}	Peak gate current	t _p = 20 μs	T _j = 150 °C	4	А	
P _{G(AV)}	Average gate power dissipation $T_j = 150 \text{ °C}$			1	W	
T _{stg} T _j	Storage junction temperature range Operating junction temperature range			- 40 to + 150 - 40 to + 150	°C	

Table 3. Electrical characteristics ($T_j = 25$ °C, unless otherwise specified)

Symbol	Test conditions	Test conditions Quadrant			Va	lue	Unit
Symbol		Quadrant	rant T835H - III MAX. 35 - III MAX. 35 - III MIN. 35 - III MIN. 35 II MAX. 35 II 80 MIN. 1000	T835H	T850H	Unit	
I _{GT} ⁽¹⁾	V _D = 12 V, R _I = 33 Ω	- -	MAX.	35	50	mA	
V _{GT}	$v_{\rm D} = 12 v, n_{\rm L} = 33.32$	- -	MAX.	1.	.0	V	
V _{GD}	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega$	- -	MIN.	0.15		V	
I _H ⁽²⁾	I _T = 500 mA		MAX.	35	75	mA	
	1 - 1 2 1	-		50	60	mA	
۲L	$I_{\rm L}$ $I_{\rm G} = 1.2 I_{\rm GT}$	II		80	110		
dV/dt ⁽²⁾	$V_D = 67\% V_{DRM,}$ gate open, $T_j = 150 \text{ °C}$		MIN.	1000	1500	V/µs	
(dl/dt)c (2)	Without snubber, $T_j = 150 \ ^{\circ}C$		MIN.	11	14	A/ms	

1. minimum I_{GT} is guaranted at 20% of I_{GT} max.

2. for both polarities of A2 referenced to A1.



Table 4.Static characteristics

Symbol	Test conditions				Unit
$V_{T}^{(1)}$	I _{TM} = 11 A, t _p = 380 μs	T _j = 25 °C	MAX.	1.5	V
V _{t0} ⁽¹⁾	Threshold voltage	T _j = 150 °C	MAX.	0.80	V
R_d ⁽¹⁾	Dynamic resistance	T _j = 150 °C	MAX.	25	mΩ
		T _j = 25 °C	MAX.	5	μA
I _{DRM}	$V_{\text{DRM}} = V_{\text{RRM}}$	T _j = 150 °C	MAX.	3.1	
I _{RRM} ⁽²⁾	$V_D/V_R = 400 V$ (at peak mains voltage)	T _j = 150 °C	MAX.	2.5	mA
	$V_D/V_R = 200 V$ (at peak mains voltage)	T _j = 150 °C	MAX.	2.0	

1. for both polarities of A2 referenced to A1

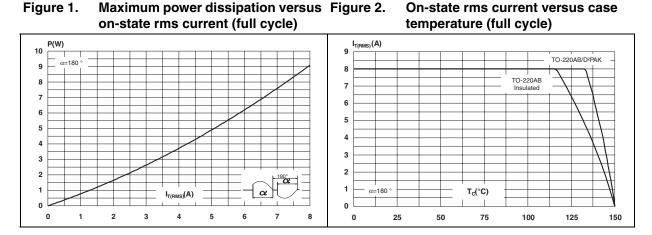
2. t_p = 380 μs

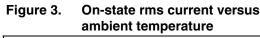
Table 5.Thermal resistance

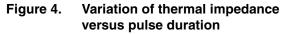
Symbol	Parameter			Value	Unit
Р	lunction to copp (AC)		D ² PAK / TO-220AB	1.85	
R _{th(j-c)}	Junction to case (AC)		TO-220AB Ins	3.7	°C/W
P	$R_{th(j-a)}$ Junction to ambient $S = 1 \text{ cm}^2$		D ² PAK	45	-0/00
H _{th(j-a)}			TO-220AB / TO-220AB Ins	60	



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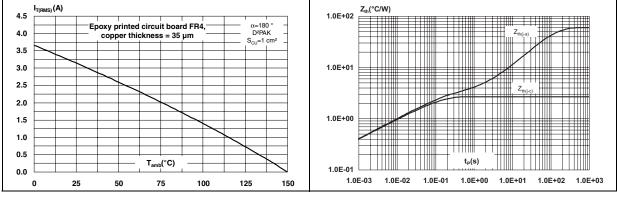
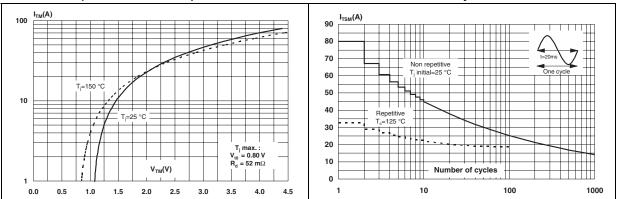
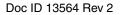


Figure 5. On-state characteristics (maximum values)

Figure 6. Surge peak on-state current versus number of cycles







2.0

1.8

1.6

1.4

1.2

1.0

0.8

0.6

0.4

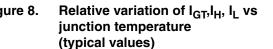
0.2

0.0

57

0.1

Figure 7. Non-repetitive surge peak on-state Figure 8. current for a sinusoidal pulse with



 I_{GT} , I_{H} , I_{L} $[T_{j}] / I_{GT}$, I_{H} , I_{L} $[T_{j}=25^{\circ}C]$

2.5

2.0

1.5

1.0

0.5

0.0

-40 -20 0 20 40 60 80 100 120 140 160

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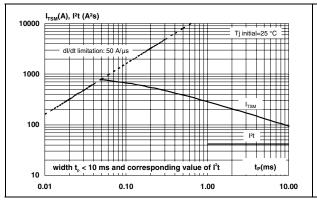
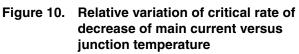


Figure 9. Relative variation of critical rate of decrease of main current (dl/dt)c versus reapplied (dV/dt)c



T_i(°C)

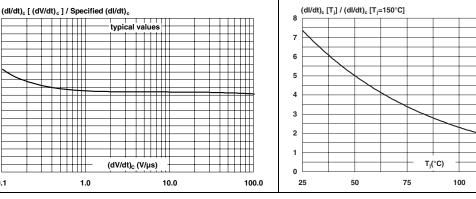


Figure 11. Leakage current versus junction temperature for different values of blocking voltage (typical values)

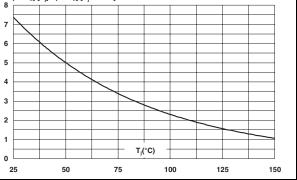
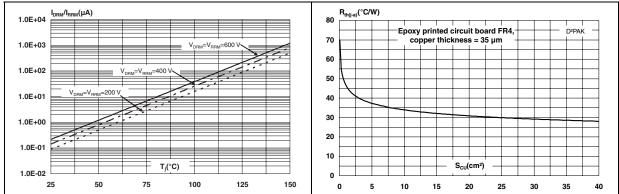


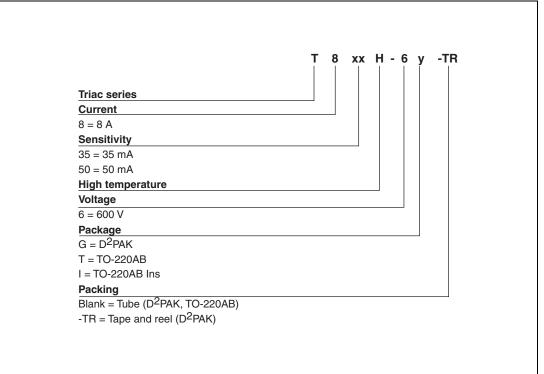
Figure 12. Variation of thermal resistance junction to ambient versus copper surface under tab



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2 Ordering information scheme

Figure 13.	Ordering	information	scheme
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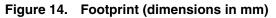
3 Package information

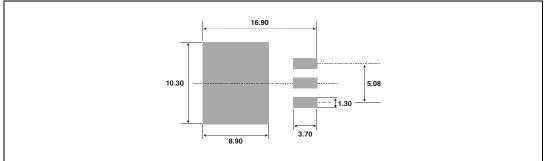
- Epoxy meets UL94, V0
- Recommended torque 0.4 to 0.6 N·m

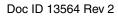
In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: <u>www.st.com</u>. ECOPACK[®] is an ST trademark.

Table 6.D²PAK dimensions

			Dimensions					
		Ref.	Mi	llimete	rs		Inches	
			Min.	Тур.	Max.	Min.	Тур.	Max.
		Α	4.30		4.60	0.169		0.181
		A1	2.49		2.69	0.098		0.106
		A2	0.03		0.23	0.001		0.009
		В	0.70		0.93	0.027		0.037
		B2	1.25	1.40		0.048	0.055	
		С	0.45		0.60	0.017		0.024
		C2	1.21		1.36	0.047		0.054
		D	8.95		9.35	0.352		0.368
G		E	10.00		10.28	0.393		0.405
	2mm min. A2	G	4.88		5.28	0.192		0.208
	FLAT ZONE	L	15.00		15.85	0.590		0.624
	V2	L2	1.27		1.40	0.050		0.055
	~ ∌ I	L3	1.40		1.75	0.055		0.069
		R		0.40			0.016	
		V2	0°		8°	0°		8°







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			Dimensions					
		Ref.	Mi	illimete	rs		Inches	
			Min.	Тур.	Max.	Min.	Тур.	Max.
		А	15.20		15.90	0.598		0.625
		a1		3.75			0.147	
	C C	a2	13.00		14.00	0.511		0.551
	b2	В	10.00		10.40	0.393		0.409
	F	b1	0.61		0.88	0.024		0.034
A		b2	1.23		1.32	0.048		0.051
		С	4.40		4.60	0.173		0.181
	c2	c1	0.49		0.70	0.019		0.027
	• •	c2	2.40		2.72	0.094		0.107
_ * • a2		е	2.40		2.70	0.094		0.106
	M	F	6.20		6.60	0.244		0.259
H ≰ b1	M ↔ c1	ØI	3.75		3.85	0.147		0.151
		14	15.80	16.40	16.80	0.622	0.646	0.661
		L	2.65		2.95	0.104		0.116
		12	1.14		1.70	0.044		0.066
		13	1.14		1.70	0.044		0.066
		М		2.60			0.102	

Table 7. TO-220AB and TO-220AB Ins dimensions



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4 Ordering information

Table 8.Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
T8xxH-6G	T8xxH 6G	D ² PAK	1.5 g	50	Tube
T8xxH-6G-TR	T8xxH 6G	D ² PAK	1.5 g	1000	Tape and reel
T8xxH-6T	T8xxH 6T	TO-220AB	2.3 g	50	Tube
T8xxH-6I	T8xxH 6l	TO-220AB Ins	2.3 g	50	Tube

5 Revision history

Table 9.	Document revision history	y
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Date	Revision	Changes
17-Apr-2007	1	First issue.
19-Sep-2011	2	Udated: Features, Description, Figure 2, Table 2 and 4.



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